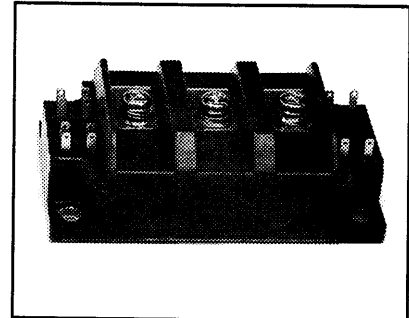
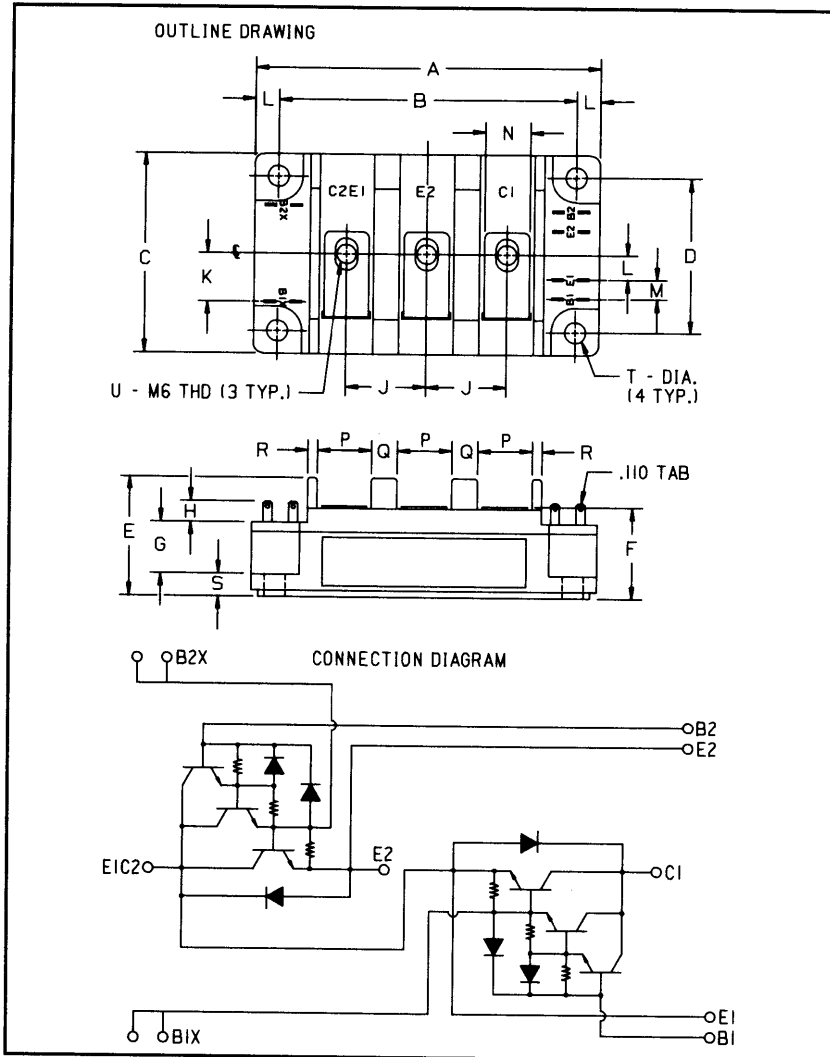


Dual Darlington Transistor Module 100 Amperes/1200 Volts



Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

Features:

- Isolated Mounting
- Planar Chips
- Discrete Fast Recovery Feedback Diode
- High Gain (h_{FE})
- Quick Connect Base-Emitter Signal Terminals
- Base-Emitter Speed-up Diodes

Applications:

- AC Motor Control
- DC Motor Control
- Switching Power Supplies
- Inverters

Ordering Information:

Example: Select the complete ten digit module part number you desire from the table - i.e. KD421210A7 is a 1200 Volt, 100 Ampere Dual Darlington Module with a gain of 100 at rated current (100 Amperes).

Outline Drawing

Dimensions	Inches	Millimeters
A	4.252 Max.	108 Max.
B	3.661 ± 0.012	93 ± 0.3
C	2.441 Max.	62 Max.
D	1.890 ± 0.012	48 ± 0.3
E	1.457	37
F	1.181 Max.	30 Max.
G	0.630	16
H	0.256 Min.	6.5 Min.
J	0.984	25
K	0.591	15

Dimensions	Inches	Millimeters
L	0.295	7.5
M	0.236	6
N	0.551	14
P	0.669	17
Q	0.315	8
R	0.118	3
S	0.276	7
T	0.256 Dia.	6.5 Dia.
U	M6 Metric	M6

Type	V _{CEO(sus)} Volts (X 100)	Current Rating Amperes (X 10)
KD42	12	10



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

KD421210A7
Dual Darlington Transistor Module
 100 Amperes/1200 Volts

Absolute Maximum Ratings, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	KD421210A7	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{\text{CEV(sus)}}$	1200	Volts
Collector-Base Voltage	V_{CBO}	1200	Volts
Emitter-Base Voltage	V_{EBO}	7	Volts
Collector-Emitter Voltage, $V_{BE} = -2\text{V}$	V_{CEV}	1200	Volts
Continuous Collector Current	I_C	100	Amperes
Diode Forward Current	I_{FM}	100	Amperes
Continuous Base Current	I_B	5	Amperes
Diode Surge Current	I_{FSM}	1000	Amperes
Power Dissipation (Each Transistor)	P_t	800	Watts
Max. Mounting Torque M6 Terminal Screws	-	26	in.-lb.
Max. Mounting Torque M6 Mounting Screws	-	26	in.-lb.
Module Weight (Typical)	-	470	Grams
V Isolation	V_{RMS}	2500	Volts

Electrical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units	
Collector Cutoff Current	I_{CEV}	$V_{\text{CE}} = 1200\text{V}, V_{\text{BE}} = -2\text{V}$	-	-	2	mA	
Emitter Cutoff Current	I_{EBO}	$V_{\text{EB}} = 7\text{V}$	-	-	400	mA	
DC Current Gain	h_{FE}	$I_C = 100\text{A}, V_{\text{CE}} = 5\text{V}$	75	-	-	-	
Diode Forward Voltage	V_{FM}	$I_{\text{FM}} = 100\text{A}$	-	-	1.8	Volts	
Collector-Emitter Saturation Voltage	$V_{\text{CE(sat)}}$	$I_C = 100\text{A}, I_B = 2\text{A}$	-	-	3.0	Volts	
Base-Emitter Saturation Voltage	$V_{\text{BE(sat)}}$	$I_C = 100\text{A}, I_B = 2\text{A}$	-	-	3.5	Volts	
Resistive	Turn-on	t_{on}	$V_{\text{CC}} = 600\text{V}$	-	-	3.0	μs
Load	Storage Time	t_s	$I_C = 100\text{A}$	-	-	15	μs
Switch Times	Fall Time	t_f	$I_{\text{B1}} = -I_{\text{B2}} = 2\text{A}$	-	-	3.0	μs

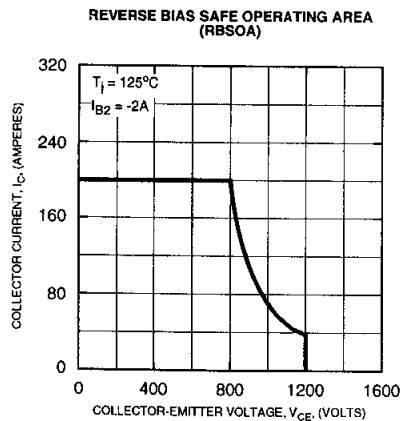
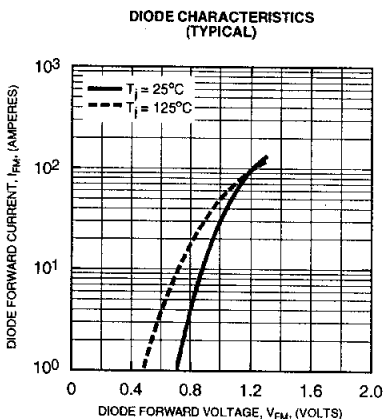
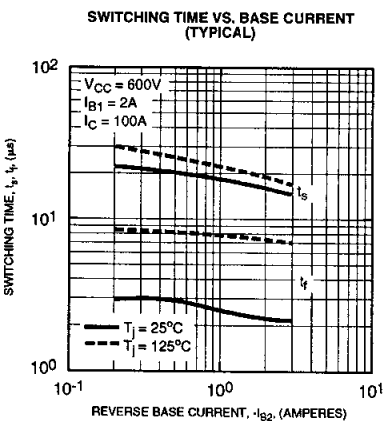
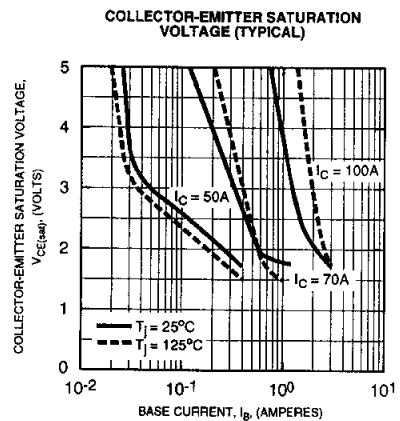
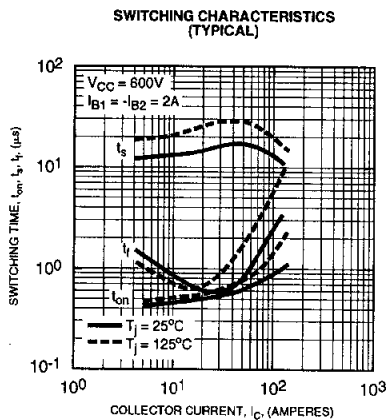
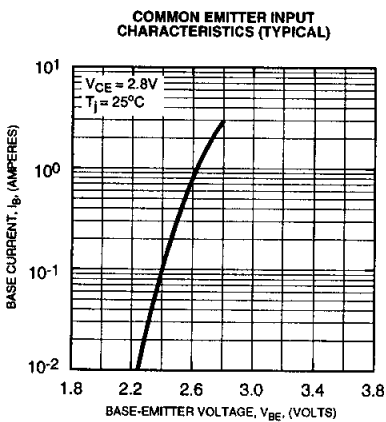
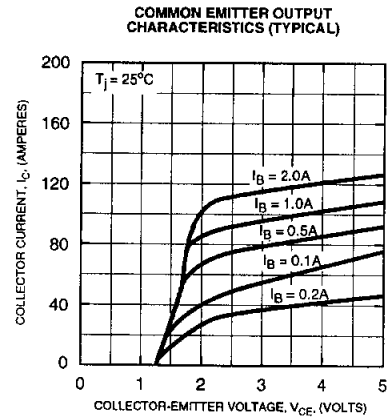
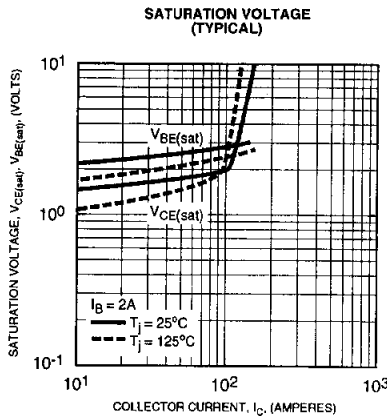
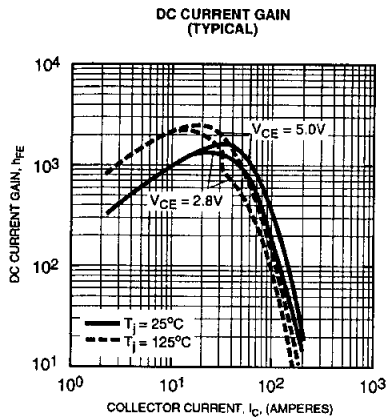
Thermal and Mechanical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Case-to-Sink	$R_{\theta(\text{c-s})}$	Per Half Module	-	-	0.075	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(\text{j-c})}$	Transistor Part	-	-	0.155	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(\text{j-c})}$	Diode Part	-	-	0.65	$^\circ\text{C/W}$



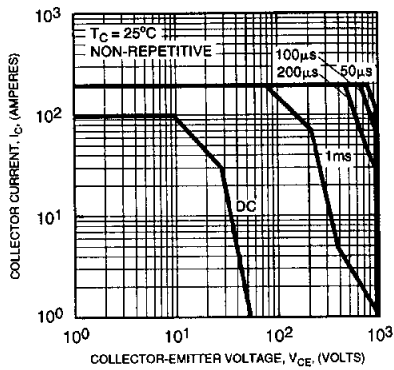
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KD421210A7
Dual Darlington Transistor Module
 100 Amperes/1200 Volts

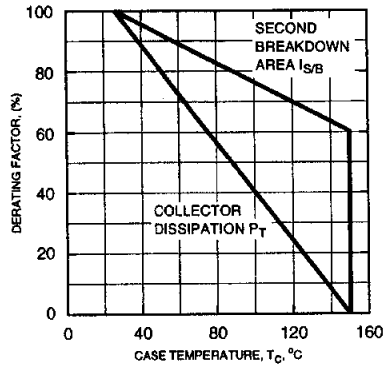


KD421210A7
Dual Darlington Transistor Module
 100 Amperes/1200 Volts

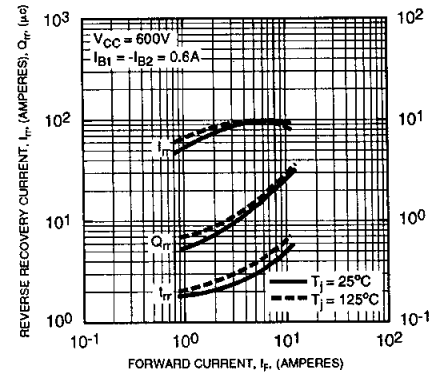
FORWARD BIAS SAFE OPERATING AREA (SOA)



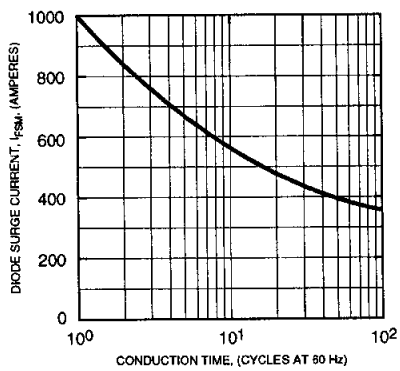
DERATING FACTOR OF SAFE OPERATING AREA (SOA)



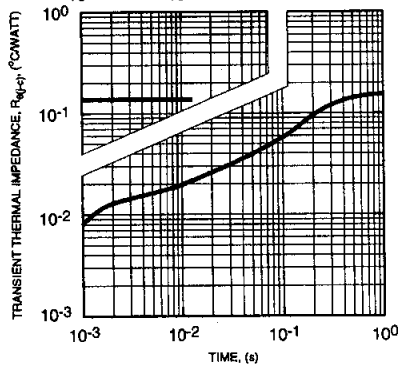
REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL)



DIODE FORWARD SURGE CURRENT



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (TRANSISTOR)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (DIODE)

